

SCT151K -650R SCT151K -800R SCT151B-650R

Po

RoHS

Technical Data Data Sheet N2049, Rev.-

SCT151 Series 12A SCRs



Description

With high ability to withstand the shock loading of large current, SCT151 series of silicon controlled rectifiers provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units	
Storage junction temperature range	T _{stg}	-	-40-150	°C	
Operating junction temperature range	Tj	-	-40-125	°C	
Repetitive peak off-state voltage(Tj=25 $^\circ\!\!{\rm C}$)	V _{DRM}	-	650/800	V	
Repetitive peak reverse voltage(Tj=25 $^{\circ}$ C)	V _{RRM}	-	650/800	V	
RMS on-state current	I _(TRMS)	DPAK(Tc=98℃) TO-220B (Non-Ins)(Tc=100℃)	12	А	
Non repetitive surge peak on-state current (tp=10ms)	I _{TSM}	-	120	А	
l²t value for fusing (tp=10ms)	l ² t	-	72	A ² s	
Repetitive rate of rise of on-state current $(I_G=2 \times I_{GT})$	dl⊤/dt	-	50	A/µs	
Peak gate current	I _{GM}	-	2	Α	
Peak gate power	Р _{GM}	-	5	W	
Average gate power dissipation	P _{G(AV)}	-	0.5	W	

http://www.smc-diodes.com - sales@ smc-diodes.com •



Technical Data Data Sheet N2049, Rev.-

SCT151K -650R SCT151K -800R SCT151B-650R



Electrical Characteristics(Tj=25 °C unless otherwise specified)

Symbol	Took Oon dition		11		
	Test Condition	MIN.	TYP.	MAX.	Unit
Igt	V -12V P -220	-	4	15	mA
V _{GT}	$V_D=12V R_L=33\Omega$	-	0.75	1.5	V
V _{GD}	$V_D = V_{DRM} T_j = 125^{\circ}C R_L = 3.3 K\Omega$	0.2	-	-	V
١L	I _G =1.2I _{GT}	-	12	40	mA
IH	I _T =500mA	-	12	30	mA
dV/dt	V _D =2/3V _{DRM} Gate Open Tj=125℃	200	400	-	V/µs

Static Characteristics

Symbol	Condition	Max.	Units
V _{TM}	I⊤=23A tp=380µs,Tj=25℃	1.6	V
I _{DRM}	V _D =V _{DRM} V _R =V _{RRM} , Tj=25 °C	10	μA
I _{RRM}	V _D =V _{DRM} V _R =V _{RRM} , Tj=125℃	1	mA

Thermal Resistances

Symbol	Cone	dition	Value	Units	
Rth(j-c)	Junction to case(AC)	DPAK	1.4	°C/W	
		TO-220B (Non-Ins)	1.3		

Ordering Information



Device	Package	Shipping
SCT151B-650R	TO-220B	50pcs/ Tube
SCT151K -650R/800R	DPAK	2500pcs/ Reel
SCT151K -650R/800RTR	DPAK	2500pcs/ Reel

• China - Germany - Korea - Singapore - United States •

http://www.smc-diodes.com - sales@ smc-diodes.com



Technical Data Data Sheet N2049, Rev.-

Marking Diagram





Where XXXXX is YYWWL

SCT151B-650R	= Part name
SCT151K-650R	= Part name
YY	= Year
WW	= Week
L	= Lot Number

Millimeters

SYMBOL

Mechanical Dimensions TO-220B(Non-Ins)



Mechanical Dimensions DPAK



	Min.	Тур.	Max.	Min.	Тур.	Max.
A	4.40		4.60	0.173		0.181
В	0.61		0.88	0.024		0.035
С	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.60		10.4	0.378		0.409
F	6.20		6.60	0.244		0.260
G		2.54			0.1	
Н	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

SYMBOL	Millimeters			Inches		
STINIBUL	Min.	Тур.	Max.	Min.	Тур.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
В	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
С	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1		5.30REF		0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
н	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7° 7°				
V2	0°		6°	0°		6°

• China - Germany - Korea - Singapore - United States •

• http://www.smc-diodes.com - sales@ smc-diodes.com •

Pò

Inches

RoHS



SCT151K -650R SCT151K -800R SCT151B-650R

Pb

α=180°

125

TO-220B(Non-Ins)

100

DPAK

RoHS

Technical Data Data Sheet N2049, Rev.-

20

5

Ratings and Characteristics Curves





FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms, and corresponding value of 1 t (dl/dt < 50A/s)





temperature

ITM (A) 100 Ti =Tin 10 Tj=25℃ Vтм (V) 1 2 3 4 5

FIG.2: RMS on-state current versus case

FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



• China - Germany - Korea - Singapore - United States • • http://www.smc-diodes.com - sales@ smc-diodes.com •



Technical Data Data Sheet N2049, Rev.-



DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..